ETR0802_004

Regulated Voltage Step-Up Charge Pump ICs

■ GENERAL DESCRIPTION

The XC9801 series are fixed regulated voltage step-up charge pump ICs which provide stable, highly efficient, positive voltages with the only external components required being 2 capacitors.

Since regulating is done via the control of the charge pump's gate voltage waveform, ripple is minimal. Output voltage is selectable in 100mV steps within a 2.5V ~ 6.0V range.

Control of the XC9802 switches to PFM (pulse skip) during light loads without affecting output impedance or ripple so that the IC is protected against drops in efficiency. Connecting the SENSE pin to the GND pin allows the IC to be used as a voltage doubler.

As well as the ultra small MSOP-8A and USP-8 packages, the small consumption current and high efficiencies of the series make the XC9801 suitable for use with all types of battery operated applications.

■ APPLICATIONS

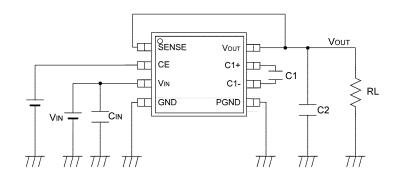
- Palm top computers, PDAs
- On board local power supplies
- Various battery powered devices

■FEATURES

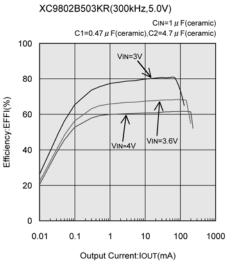
Input Voltage Range	: 1.8V ~ 5.5V
Output Voltage Range	: 2.5V ~ 6.0V
Small Input Current	: 80 µ A (no load:XC9802)
Output Current	: 80mA (3.6V→5.0V step-up)
Oscillation Frequency	: 300kHz
Stand-by Current (CE 'L')	: 2.0 µ A (MAX.)
PFM Operation During Light	t Loads (XC9802)
CE (Chip Enable) Function	
Can be used as a step-up d	oubler (sense = 0V)
Packages	: MSOP-8A, USP-8
Environmentally Friendly	: EU RoHS Compliant, Pb Free

TYPICAL APPLICATION CIRCUIT

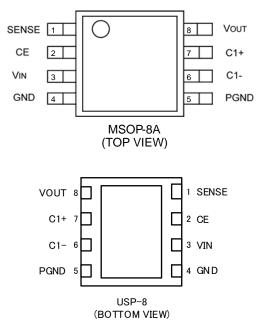
Regulation Output



■TYPICAL PERFORMANCE CHARACTERISTICS



■ PIN CONFIGURATION



■ PIN ASSIGNMENT

PIN NU	JMBER	PIN NAME	FUNCTION
USP-8	MSOP-8A		renerien
1	1	SENSE	Output Voltage Monitor
2	2	CE	Chip Enable (High Active)
3	3	Vin	Input (Power Supply)
4	4	GND	Ground
5	5	Pgnd	Power Ground
6	6	C1-	External Capacitor - Pin
7	7	C1+	External Capacitor + Pin
8	8	Vout	Output

■PRODUCT CLASSIFICATION

Selection Guide

SERIES	PULSE SKIP MODE
XC9801	Not Available
XC9802	Available

Ordering Information

XC9801/XC9802 123456-7 (*1)

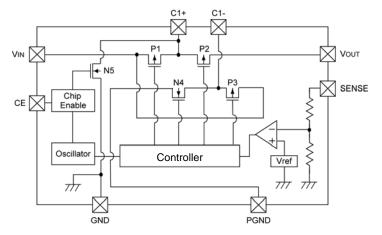
DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
1	True Logic Level at CE Pin	В	Positive
	Output Voltage	50	Standard voltage Vou⊤=5.0V→②=5, ③=0
23	Oulput voltage	25 ~ 60	Semi-custom voltage e.g. Vou⊤=2.5V→②=2, ③=5
4	Oscillation Frequency	3	300kHz
		KR	MSOP-8A (1,000/Reel)
56-7	Packages (Order Unit)	KR-G	MSOP-8A (1,000/Reel)
		DR	USP-8 (3,000/Reel)
		DR-G	USP-8 (3,000/Reel)

Regulated output voltage function cannot be used by the following input voltage condition:

VIN < (VOUT/2), or VIN ≧ VOUT

(*1) The "-G" suffix denotes Halogen and Antimony free as well as being fully RoHS compliant.

■BLOCK DIAGRAM



(1) Basic Operations

Using the XC9801/02' s clock generated by the internal oscillator, a step-up charge pump operation can be brought about as a result of the alternate switching between operating conditions where P1 & N4 are ON with P2 & P3 OFF (or) P1 & N4 are OFF with P2 & P3 ON. By connecting the SENSE pin to VOUT, output voltage can be feedback and the difference between the feedback voltage and the reference voltage (Vref) are compared by the internal operational amplifier. Output voltage can be stabilized (* 2) by controlling P3' s gate voltage waveform via the signal generated by the internal amplifier.

Please note that this stabilizing function will not operate with VIN < (VOUT/2) or VIN ≧ VOUT.

By connecting SENSE to ground, the output stability function, as described above, can be halted and the IC can be used as a step-up doubler.

* **2** : As a result of P3 gradually reaching an ON state with each clock (signal), rush current is controlled, the ripple decreases and with the combination of the independent phase compensation circuit, output voltage is stabilized

(2) Stand-by

When the voltage at CE (chip enable) is 'low' (0V), P1, P2 & P3 will be OFF with N4 & N5 ON. The external capacitor C1 will discharge and impedance at VOUT will be high.

(3) PFM (Pulse Skip) Operations

Whilst maintaining output voltage, the XC9802 provides the added security of protection against drops in efficiency during light loads as a result of the pulse, generated by the internal oscillator, being skipped and the operating frequency being changed.

			Ta =	= 25°C, GND = 0V
PARAMETE	R	SYMBOL	CONDITIONS	UNITS
VIN pin Volta	ge	Vin	-0.3~6.0	V
Vout pin Volta	age	Vout	-0.3~12.0	V
C1 + pin Volta	age	C1+	-0.3~Vout+0.3	V
C1 - pin Volta	C1 - pin Voltage		-0.3~Vout+0.3	V
CE pin Volta	CE pin Voltage VCE		-0.3~VIN+0.3	V
VOUT Pin Output	VOUT Pin Output Current		200	mA
Power Dissipation	MSOP-8A	Pd	150	mW
Fower Dissipation	USP-8	FU	120	IIIVV
Operating Temperature Range		Topr	$-40 \sim +85$	٦°
Storage Temperatu	re Range	Tstg	-40 ~ +125	°C

■ABSOLUTE MAXIMUM RATINGS

■ ELECTRICAL CHARACTERISTICS

XC9801B503KR Vout=5.0V

XC9801B503KR Vout=5.0V						٦	īa=25℃
PARAMETER	SYMBOL	CONE	DITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	Vout	Regulation Output	IOUT=1mA	4.875	5.000	5.125	V
Load Regulation	ΔVουτ	Regulation Output	1mA≦Iouт≦80mA	-100	-	100	mV
Operating Voltage Range	Vin	Doubler Output, Vo	JT>VIN × 2 × 0.95	1.8	-	5.5	V
Supply Current	ldd	VIN=3.6V, External C SENSE=0V, VOUT=V	omponents=Cın only, ın	1	3	6	mA
Stand-by Current	Istb	CE=0V		-	-	2.0	μA
Oscillation Frequency	FOSC	External Component=CIN only, SENSE=0V, VOUT open		255	300	345	kHz
Output Impedance	Rout	Doubler Output	IOUT=10mA	-	20	40	Ω
Input Current	lin	Doubler Output		-	5	-	mA
Input Current	lin2	Regulation Output		-	1.5	-	mA
Voltage Converting Efficiency	Veffi	Doubler Output		95	99	-	%
	EFFI	Doubler Output	IOUT=10mA	73	78	-	%
Power Converting Efficiency	EFFI2	Regulation Output	IOUT=1mA	-	40	-	%
	EFFI3	Regulation Output	IOUT=80mA	64	69	-	%
CE / 'H' Level Voltage	VCEH			1.5	-	-	V
CE / 'L' Level Voltage	VCEL			-	-	0.25	V
CE / Input Current	ICE	VIN=5.5V, SENSE=0V, External Components=CIN only		-2.0	-	2.0	μA

Test Conditions: Unless otherwise stated, Typical Application Circuit, VIN=3.6V, GND=0V, CE=VIN, No Load, SENSE=Vout (Regulation Output)

XC9802B503KR Vout=5.0V

XC9802B503KR Vout=5.0V							Ta=25°C
PARAMETER	SYMBOL	COND	ITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	Vout	Regulation Output	IOUT=1mA	4.875	5.000	5.125	V
Load Regulation	ΔVουτ	Regulation Output	1mA≦Iout≦80mA	-100	-	100	mV
Operating Voltage Range	Vin	Doubler Output, Vou	JT >VIN × 2 × 0.95	1.8	-	5.5	V
Supply Current	IDD	VIN=3.6V, External C SENSE=0V, Vout=\	Components=CIN only, /IN	1	3	6	mA
Stand-by Current	Istb	CE=0V		-	-	2.0	μA
Oscillation Frequency	FOSC	External Component = CIN only, SENSE=0V, VOUT open		255	300	345	kHz
Switching Pulse Frequency	FOSC2	Regulation Output	IOUT=1mA	-	10	-	kHz
Output Impedance	Rout	Doubler Output	IOUT=10mA	-	20	40	Ω
Input Current	lin	Doubler Output		-	5	-	mA
Input Current	lin2	Regulation Output		-	0.08	-	mA
Voltage Converting Efficiency	Veffi	Doubler Output		98	99	-	%
	EFFI	Doubler Output	IOUT=10mA	73	78	-	%
Power Converting Efficiency	EFFI2	Regulation Output	IOUT=1mA	-	59	-	%
	EFFI3	Regulation Output	Iout=80mA	64	69	-	%
CE / 'H' Level Voltage	Vсен			1.5	-	-	V
CE / 'L' Level Voltage	VCEL			-	-	0.25	V
CE / Input Current	ICE	VIN=5.5V, SENSE=0V, External Components=CIN only		-2.0	-	2.0	μA

Test Conditions: Unless otherwise stated, Typical Application Circuit, VIN=3.6V, GND=0V, CE=VIN, No Load, SENSE=Vout (Regulation Output)

Ta-25°C

■ ELECTRICAL CHARACTERISTICS (Continued)

XC9801B333KR VOUT=3.3V

XC9001D555111 V001=5.5V							la=25°C
PARAMETER	SYMBOL	COND	ITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	Vout	Regulation Output	IOUT=1mA	3.218	3.300	3.383	V
Load Regulation	ΔVout	Regulation Output	1mA≦Iouт≦2mA	-66	-	66	mV
Operating Voltage Range	Vin	Doubler Output, Vol	IT>VIN × 2 × 0.95	1.8	-	5.5	V
Supply Current	IDD	VIN=3.6V, External c SENSE=0V, VOUT=V	omponents=CiN only, /in	1	3	6	mA
Stand-by Current	ISTB	CE=0V		-	-	2.0	μA
Oscillation Frequency	FOSC	External component=CIN only, SENSE=0V, VOUT open		255	300	345	kHz
Output Impedance	Rout	Doubler Output	IOUT=10mA	-	20	40	Ω
Input Current	lin	Doubler Output		-	5	-	mA
	lin2	Regulation Output		-	1.1	-	mA
Voltage Converting Efficiency	Veffi	Doubler Output		95	99	-	%
	EFFI	Doubler Output	IOUT=10mA	73	78	-	%
Power Converting Efficiency	EFFI2	Regulation Output	IOUT=1mA	-	40	-	%
	EFFI3	Regulation Output	IOUT=32mA	64	69	-	%
CE / 'H' Level Voltage	VCEH			1.5	-	-	V
CE / 'L' Level Voltage	VCEL			-	-	0.25	V
CE / Input Current	ICE	VIN=5.5V, SENSE=0 External Component		-2.0	-	2.0	μA

Test Conditions: Unless otherwise stated, Typical Application Circuit, VIN=2.376V,

GND=0V, CE=VIN, No Load, SENSE=Vout (Regulation Output)

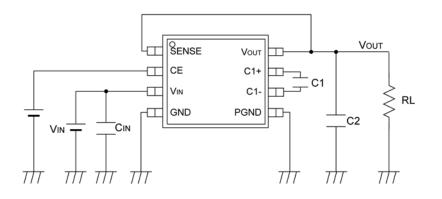
XC9802B333KR Vout=3.3V

XC9802B333KR VOUT=3.3V						r	a=25℃
PARAMETER	SYMBOL	COND	ITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	Vout	Regulation Output	Iout=1mA	3.218	3.300	3.383	V
Load Regulation	ΔVουτ	Regulation Output	1mA≦Iouт≦32mA	-66	-	66	mV
Operating Voltage Range	Vin	Doubler Output, Vou	T >VIN × 2 × 0.95	1.8	-	5.5	V
Supply Current	IDD	VIN=3.6V, External C SENSE=0V, Vout=VII	Components=CเN only, ง	1	3	6	mA
Stand-by Current	Istb	CE=0V		-	-	2.0	μA
Oscillation Frequency	FOSC	External Component = CIN only, SENSE=0V, Vout open		255	300	345	kHz
Switching Pulse Frequency	FOSC2	Regulation Output	Iout=1mA	-	10		kHz
Output Impedance	Rout	Doubler Output	IOUT=10mA	-	20	40	Ω
Innut Current	lin	Doubler Output		-	5	-	mA
Input Current	lin2	Regulation Output		-	0.08	-	mA
Voltage Converting Efficiency	Veffi	Doubler Output		98	99	-	%
	EFFI	Doubler Output	IOUT=10mA	73	78	-	%
Power Converting Efficiency	EFFI2	Population Output	Iout=1mA	-	63	-	%
	EFFI3	Regulation Output	IOUT=32mA	64	69	-	%
CE / 'H' Level Voltage	VCEH			1.5	-	-	V
CE / 'L' Level Voltage	VCEL			-	-	0.25	V
CE / Input Current	ICE	VIN=5.5V, SENSE=0 External Component	,	-2.0	-	2.0	μA

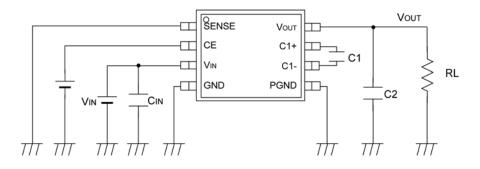
Test Conditions: Unless otherwise stated, Typical Application Circuit, VIN=2.376V, GND=0V, CE=VIN, No Load, SENSE=Vout (Regulation Output)

■TYPICAL APPLICATION CIRCUITS

① Regulation Output



2 Doubler Output



External Components: CIN=1 μ F (Ceramic Capacitor: TAIYO YUDEN) C1=0.47 μ F (Ceramic Capacitor: TAIYO YUDEN) C2=4.7 μ F (Ceramic Capacitor: TAIYO YUDEN)

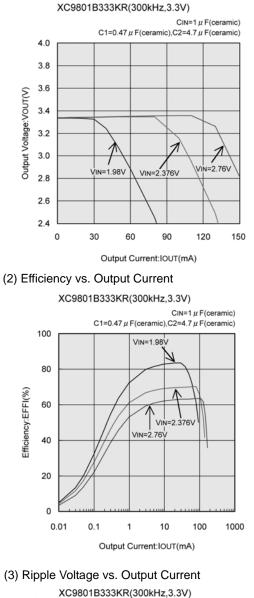
Note: The XC9801 series are step-up charge pump voltage doublers which provide regulated output voltage. The application circuit of the doubler output (②) halts the regulated output function and operates as a normal voltage doubler.

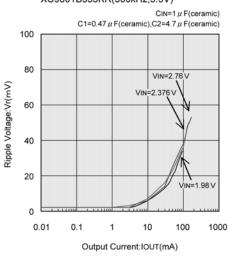
The output voltage is stable when connected as in (①) above, except when VIN < (VOUT / 2) and VIN ≧ VOUT.

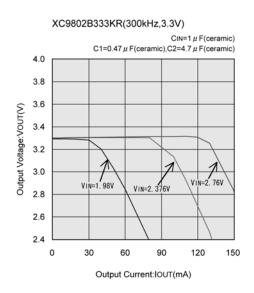
■TYPICAL PERFORMANCE CHARACTERISTICS

•XC9801B333KR (300kHz, 3.3V)

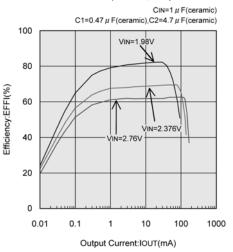
(1) Output Voltage vs. Output Current



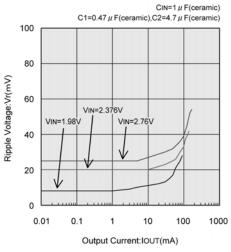




XC9802B333KR(300kHz,3.3V)



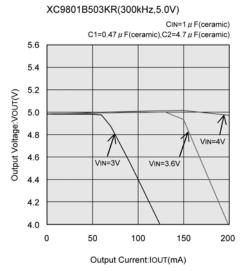
XC9802B333KR(300kHz,3.3V)



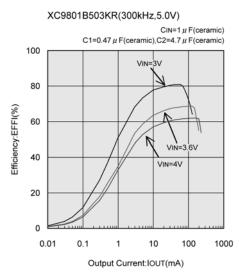
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

•XC9801B503KR (300kHz, 5.0V)

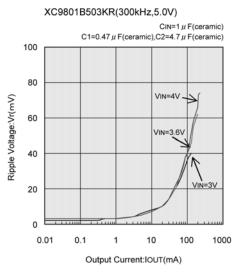
(1) Output Voltage vs. Output Current

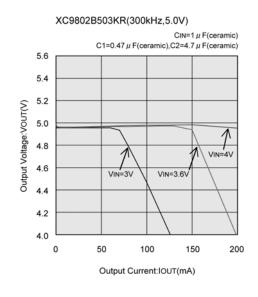


(2) Efficiency vs. Output Current

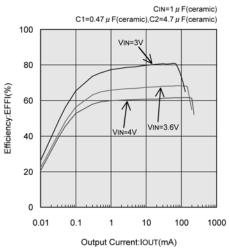


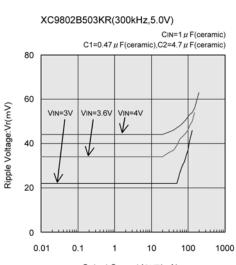
(3) Ripple Voltage vs. Output Current





XC9802B503KR(300kHz,5.0V)



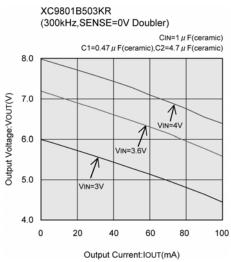


Output Current:IOUT(mA)

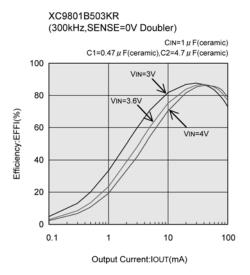
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

●XC9801B503KR (300kHz, SENSE=0V, Doubler)

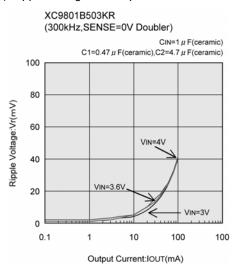
(1) Output Voltage vs. Output Current



(2) Efficiency vs. Output Current



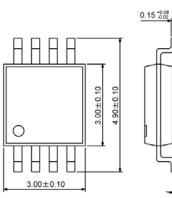
(3) Ripple Voltage vs. Output Current

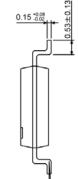


XC9801/XC9802 Series

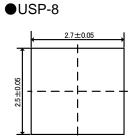
■ PACKAGING INFORMATION

●MSOP-8A

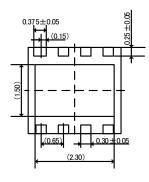




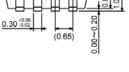
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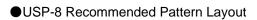


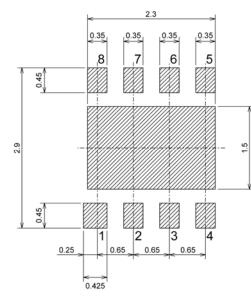




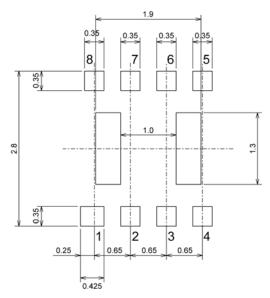
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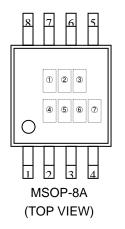


●USP-8 Recommended Metal Mask Design



■MARKING RULE

●MSOP-8A



OUSP-8

1	$\mathbf{)}$		[8
2	4	Θ		7
3	 56	23	[6
4	 9		[]]	5

USP-8 (TOP VIEW)

① represents product series

MARK	PRODUCT SERIES
2	XC9801Bxx3xx
3	XC9802Bxx3xx

2 represents true logic level at the CE pin

MARK	PRODUCT SERIES
В	XC9801/XC9802Bxx3xx

34 represents output voltage

MARK			
3	4	VOLTAGE (V)	PRODUCT SERIES
3	3	3.3	XC9801/XC9802B333xx
5	0	5.0	XC9801/XC9802B503xx

⑤ represents oscillation frequency

MARK	OSCILLATION FREQUENCY (kHz)	PRODUCT SERIES
3	300	XC9801/XC9802Bxx3xx

67 represents production lot number

01~09, 0A~0Z, 11~9Z, A1~A9, AA~AZ, B1~ZZ in order.

(G, I, J, O, Q, W excluded)

* No character inversion used.

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